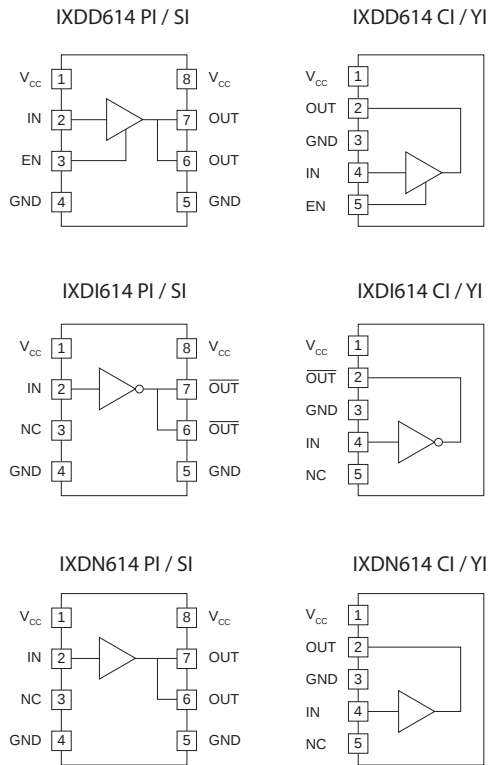


1. Specifications	3
1.1 Pin Configurations	3
1.2 Pin Definitions	3
1.3 Absolute Maximum Ratings	3
1.4 Recommended Operating Conditions	3
1.5 Electrical Characteristics: $T_A = 25^\circ\text{C}$	4
1.6 Electrical Characteristics: $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	5
1.7 Thermal Characteristics	6
2. Performance	6
2.1 Timing Diagrams	6
2.2 Characteristics Test Diagram	6
3. Block Diagrams & Truth Tables	7
3.1 IXDD614	7
3.2 IXDI614	7
3.3 IXDN614	7
4. Typical Performance Characteristics	8
5. Manufacturing Information	11
5.1 Moisture Sensitivity	11
5.2 ESD Sensitivity	11
5.3 Soldering Profile	11
5.4 Board Wash	11
5.5 Mechanical Dimensions	12
5.5.1 SI (8-Pin Power SOIC with Exposed Metal Back)	12
5.5.2 SI Package Tape & Reel Information	12
5.5.3 YI (5-Pin TO-263)	13
5.5.4 CI (5-Pin TO-220)	13
5.5.5 PI (8-Pin DIP)	14

1 Specifications

1.1 Pin Configurations



1.2 Pin Definitions

Pin Name	Description
IN	Logic Input
EN	Output Enable - Drive pin low to disable output, and force output to a high impedance state
OUT	Output - Sources or sinks current to turn-on or turn-off a discrete MOSFET or IGBT
$\overline{\text{OUT}}$	Inverted Output - Sources or sinks current to turn-on or turn-off a discrete MOSFET or IGBT
V_{CC}	Supply Voltage - Provides power to the device
GND	Ground - Common ground reference for the device
NC	Not connected

Note: IXYS Integrated Circuits Division recommends that the exposed metal pad on the back of the “SI” package be connected to GND. The pad is not suitable for carrying current.

1.3 Absolute Maximum Ratings

Parameter	Symbol	Minimum	Maximum	Units
Supply Voltage	V_{CC}	-0.3	40	V
Input Voltage	V_{IN}, V_{EN}	-5	$V_{CC}+0.3$	V
Output Current	I_{OUT}	-	± 14	A
Junction Temperature	T_J	-55	+150	°C
Storage Temperature	T_{STG}	-65	+150	°C

Unless stated otherwise, absolute maximum electrical ratings are at 25°C

Absolute maximum ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

1.4 Recommended Operating Conditions

Parameter	Symbol	Range	Units
Supply Voltage	V_{CC}	4.5 to 35	V
Operating Temperature Range	T_A	-40 to +125	°C

1.5 Electrical Characteristics: $T_A = 25^\circ\text{C}$

Test Conditions: $4.5\text{V} \leq V_{CC} \leq 35\text{V}$ (unless otherwise noted).

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Input Voltage, High	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	V_{IH}	3.0	-	-	V
Input Voltage, Low	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	V_{IL}	-	-	0.8	
Input Current	$0\text{V} \leq V_{IN} \leq V_{CC}$	I_{IN}	-	-	± 10	μA
EN Input Voltage, High	IXDD614 only	V_{ENH}	$2/3V_{CC}$	-	-	V
EN Input Voltage, Low	IXDD614 only	V_{ENL}	-	-	$1/3V_{CC}$	
Output Voltage, High	-	V_{OH}	$V_{CC}-0.025$	-	-	V
Output Voltage, Low	-	V_{OL}	-	-	0.025	
Output Resistance, High State	$V_{CC}=18\text{V}, I_{OUT}=-100\text{mA}$	R_{OH}	-	0.4	0.8	Ω
Output Resistance, Low State	$V_{CC}=18\text{V}, I_{OUT}=100\text{mA}$	R_{OL}	-	0.3	0.6	
Output Current, Continuous	Limited by package power dissipation	I_{DC}	-	-	± 4	A
Rise Time	$C_{LOAD}=15\text{nF}, V_{CC}=18\text{V}$	t_R	-	25	35	ns
Fall Time	$C_{LOAD}=15\text{nF}, V_{CC}=18\text{V}$	t_F	-	18	25	
On-Time Propagation Delay	$C_{LOAD}=15\text{nF}, V_{CC}=18\text{V}$	$t_{ONDELAY}$	-	50	70	
Off-Time Propagation Delay	$C_{LOAD}=15\text{nF}, V_{CC}=18\text{V}$	$t_{OFFDELAY}$	-	50	70	
Enable to Output-High Delay Time	IXDD614 only	t_{ENOH}	-	31	60	
Disable to High Impedance State Delay Time	IXDD614 only	t_{DOLD}	-	44	70	
Enable Pull-Up Resistor	IXDD614 only	R_{EN}	-	200	-	$\text{k}\Omega$
Power Supply Current	$V_{CC}=18\text{V}, V_{IN}=3.5\text{V}$	I_{CC}	-	1	2	mA
	$V_{CC}=18\text{V}, V_{IN}=0\text{V}$		-	<1	10	
	$V_{CC}=18\text{V}, V_{IN}=V_{CC}$		-	<1	10	

1.6 Electrical Characteristics: $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$

Test Conditions: $4.5\text{V} \leq V_{CC} \leq 35\text{V}$.

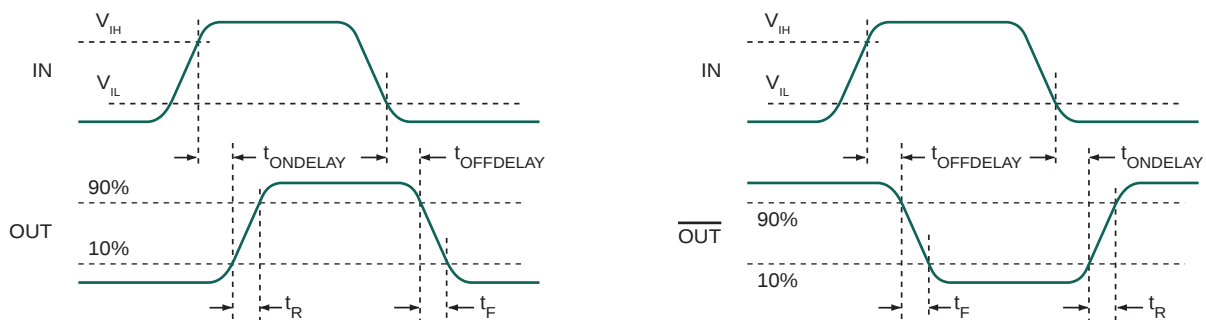
Parameter	Conditions	Symbol	Minimum	Maximum	Units
Input Voltage, High	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	V_{IH}	3.3	-	V
Input Voltage, Low	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	V_{IL}	-	0.65	
Input Current	$0\text{V} \leq V_{IN} \leq V_{CC}$	I_{IN}	-	± 10	μA
Output Voltage, High	-	V_{OH}	$V_{CC}-0.025$	-	V
Output Voltage, Low	-	V_{OL}	-	0.025	
Output Resistance, High State	$V_{CC}=18\text{V}$, $I_{OUT}=-100\text{mA}$	R_{OH}	-	1.5	Ω
Output Resistance, Low State	$V_{CC}=18\text{V}$, $I_{OUT}=100\text{mA}$	R_{OL}	-	1.2	
Output Current, Continuous	Limited by package power dissipation	I_{DC}	-	± 1	A
Rise Time	$C_{LOAD}=15\text{nF}$, $V_{CC}=18\text{V}$	t_R	-	50	ns
Fall Time	$C_{LOAD}=15\text{nF}$, $V_{CC}=18\text{V}$	t_F	-	40	
On-Time Propagation Delay	$C_{LOAD}=15\text{nF}$, $V_{CC}=18\text{V}$	$t_{ONDELAY}$	-	90	
Off-Time Propagation Delay	$C_{LOAD}=15\text{nF}$, $V_{CC}=18\text{V}$	$t_{OFFDELAY}$	-	90	
Enable to Output-High Delay Time	IXDD614 only	t_{ENOH}	-	75	
Disable to High Impedance State Delay Time	IXDD614 only	t_{DOLD}	-	85	
Power Supply Current	$V_{CC}=18\text{V}$, $V_{IN}=3.5\text{V}$	I_{CC}	-	3	mA
	$V_{CC}=18\text{V}$, $V_{IN}=0\text{V}$		-	150	μA
	$V_{CC}=18\text{V}$, $V_{IN}=V_{CC}$		-	150	

1.7 Thermal Characteristics

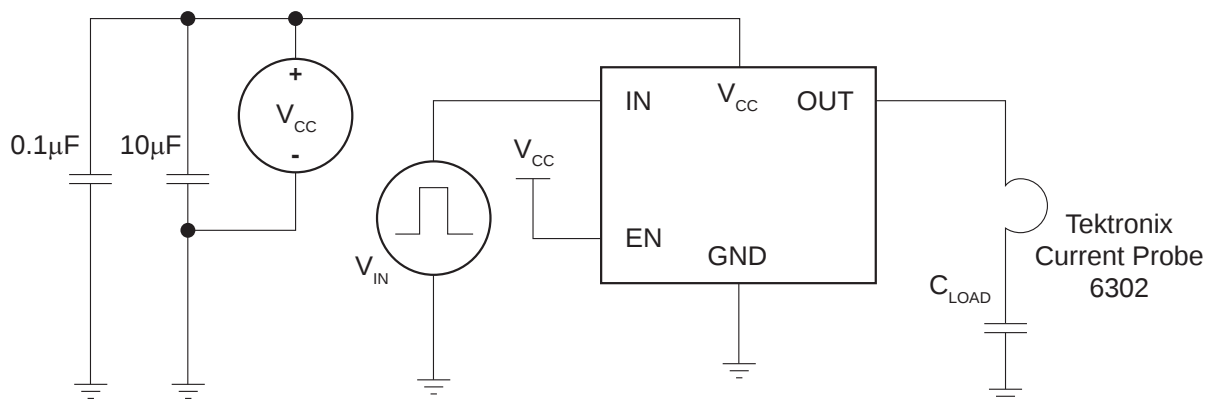
Package	Parameter	Symbol	Rating	Units
CI (5-Pin TO-220)	Thermal Impedance, Junction-to-Ambient	θ_{JA}	36	°C/W
PI (8-Pin DIP)			125	
SI (8-Pin Power SOIC)			85	
YI (5-Pin TO-263)			46	
CI (5-Pin TO-220)	Thermal Impedance, Junction-to-Case	θ_{JC}	3	°C/W
SI (8-Pin Power SOIC)			10	
YI (5-Pin TO-263)			2	

2 Performance

2.1 Timing Diagrams

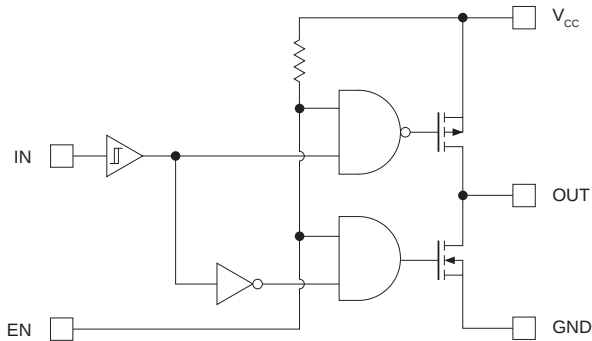


2.2 Characteristics Test Diagram



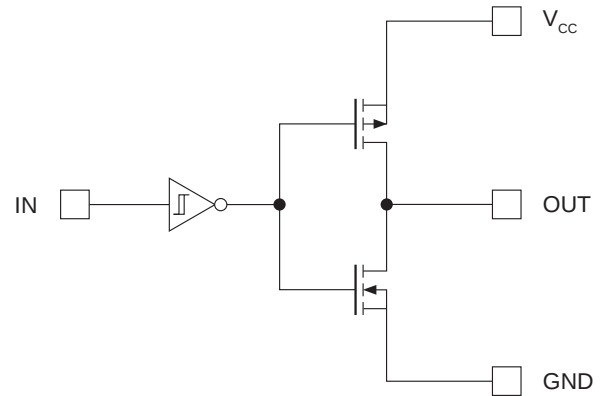
3 Block Diagrams & Truth Tables

3.1 IXDD614



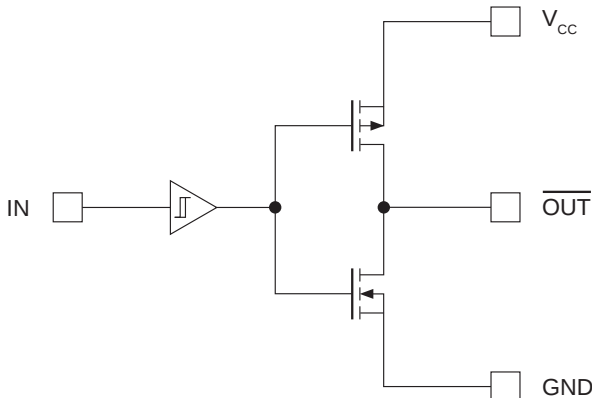
IN	EN	OUT
0	1 or open	0
1	1 or open	1
x	0	Z

3.3 IXDN614



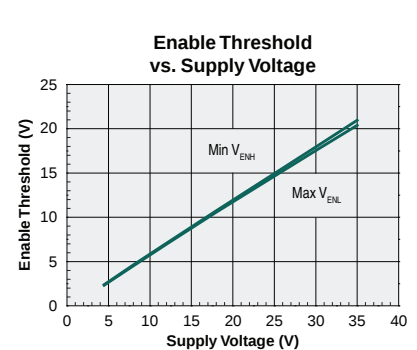
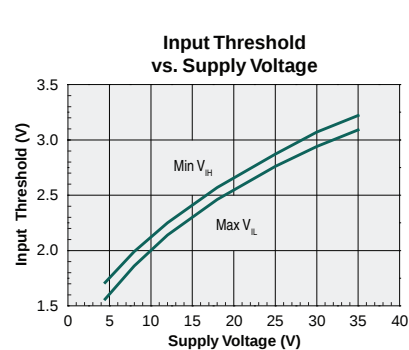
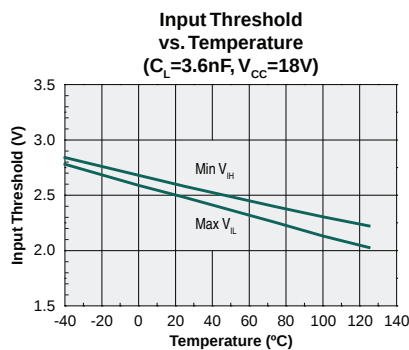
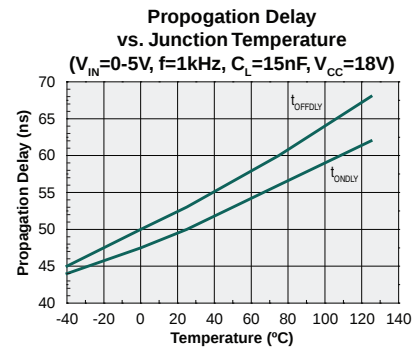
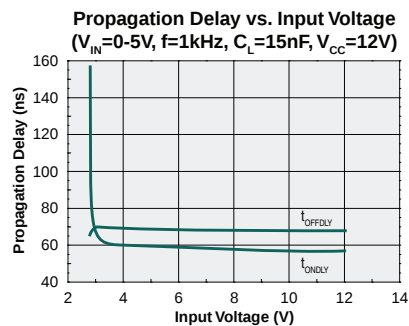
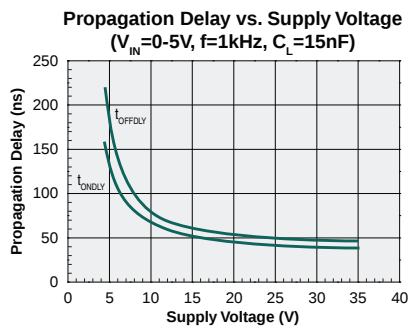
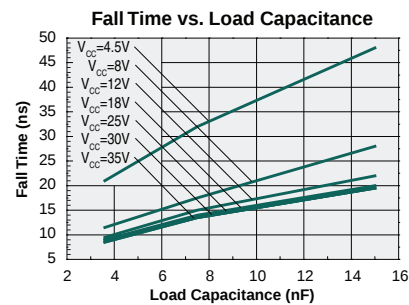
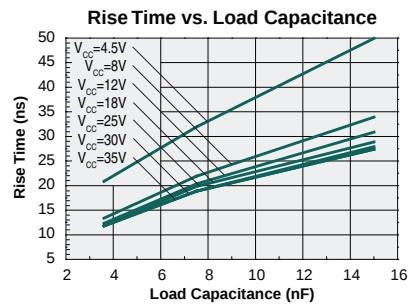
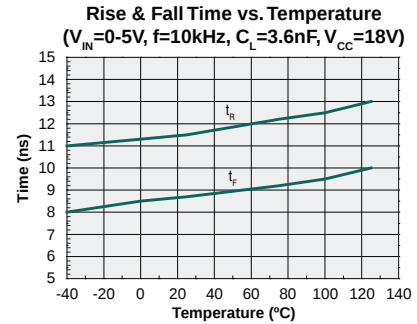
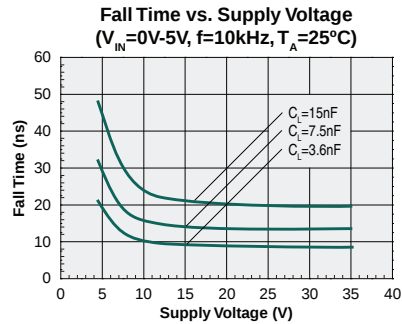
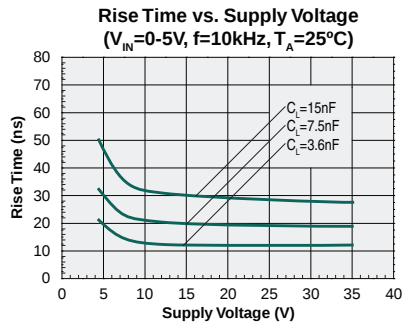
IN	OUT
0	0
1	1

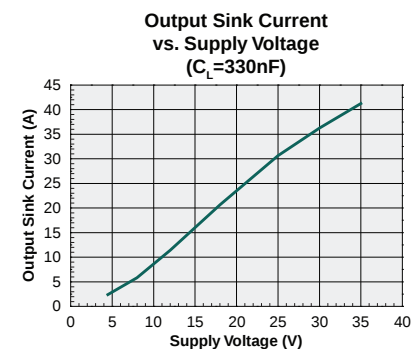
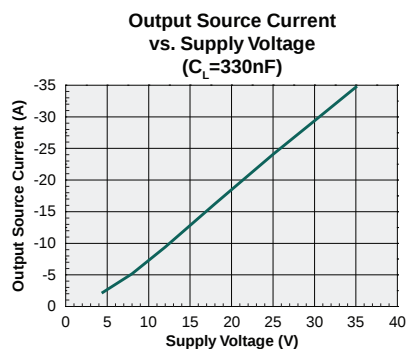
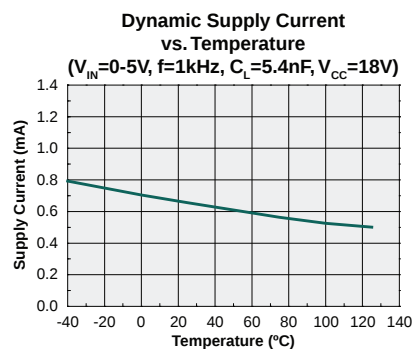
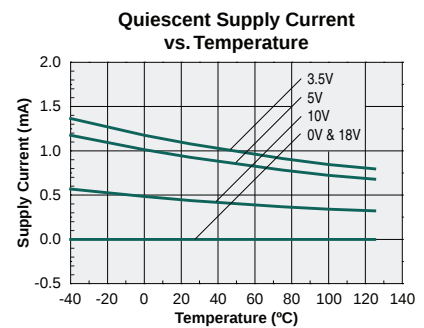
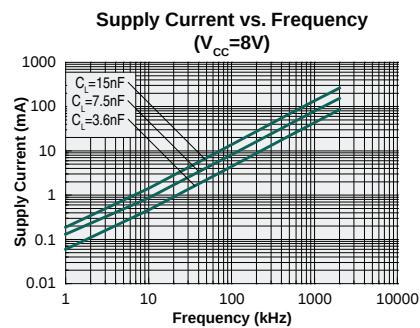
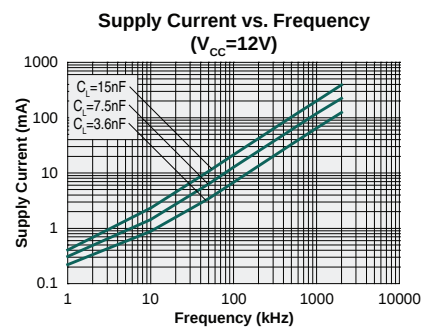
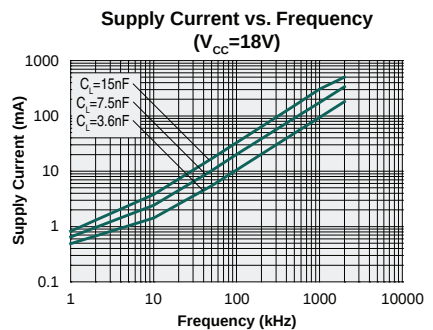
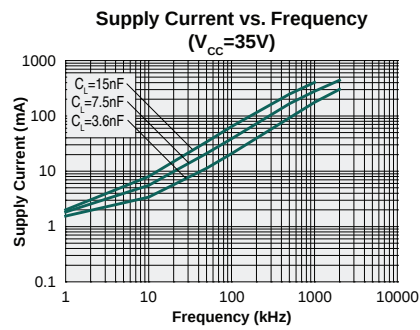
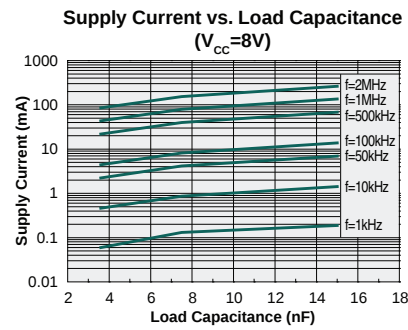
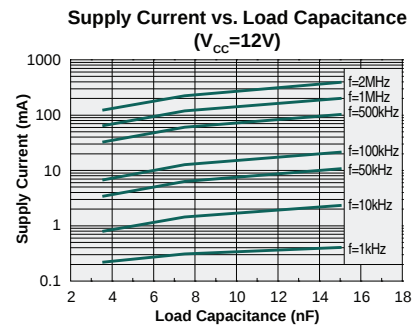
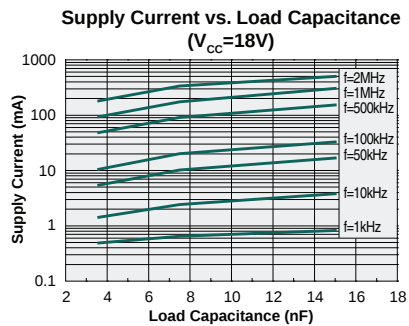
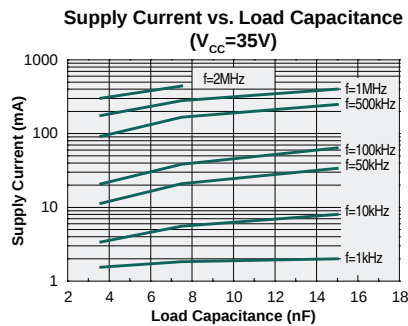
3.2 IXDI614

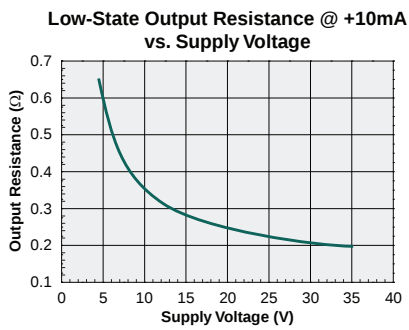
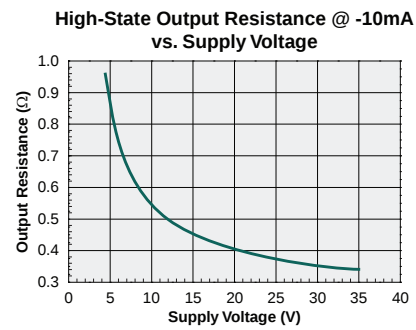
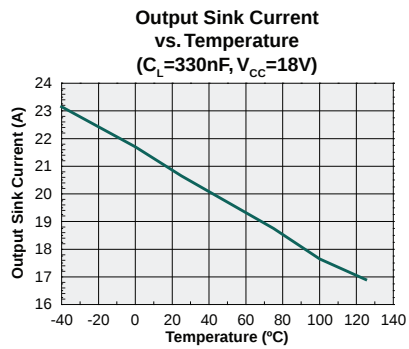
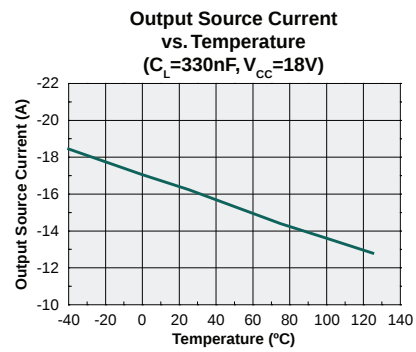


IN	$\overline{\text{OUT}}$
0	1
1	0

4 Typical Performance Characteristics







5 Manufacturing Information

5.1 Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation.

We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
IXD_614SI / IXD_614PI / IXD_614CI	MSL 1
IXD_614YI	MSL 3

5.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

5.3 Soldering Profile

Provided in the table below is the Classification Temperature (T_C) of this product and the maximum dwell time the body temperature of this device may be ($T_C - 5$)°C or greater. The classification temperature sets the Maximum Body Temperature allowed for this device during lead-free reflow processes. For through-hole devices, and any other processes, the guidelines of J-STD-020 must be observed.

Device	Classification Temperature (T_C)	Dwell Time (t_p)	Max Reflow Cycles
IXD_614CI	245°C	30 seconds	1
IXD_614YI	245°C	30 seconds	3
IXD_614PI	250°C	30 seconds	3
IXD_614SI	260°C	30 seconds	3

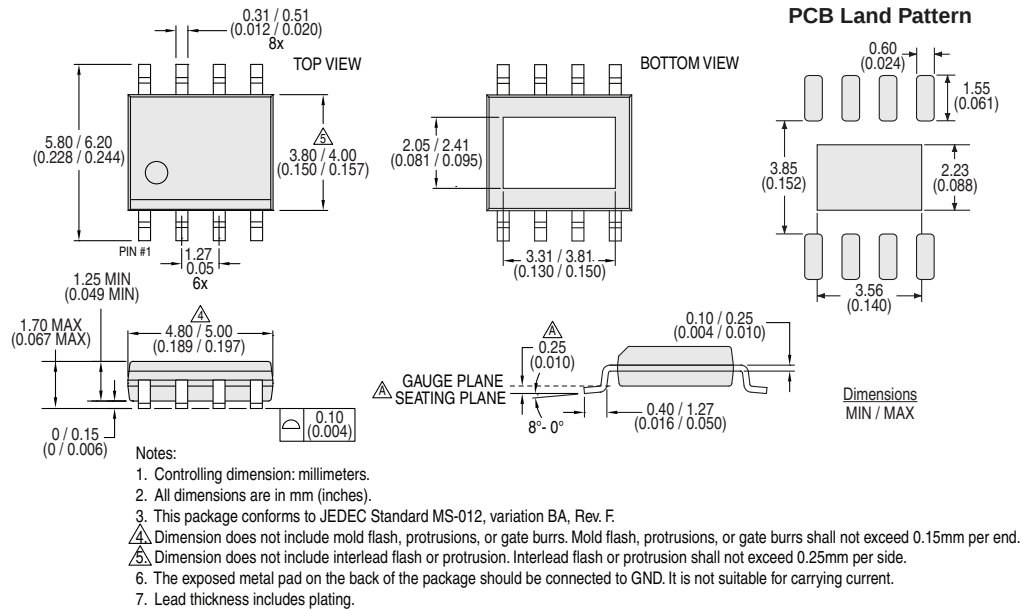
5.4 Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to flux or solvents that are Chlorine- or Fluorine-based.

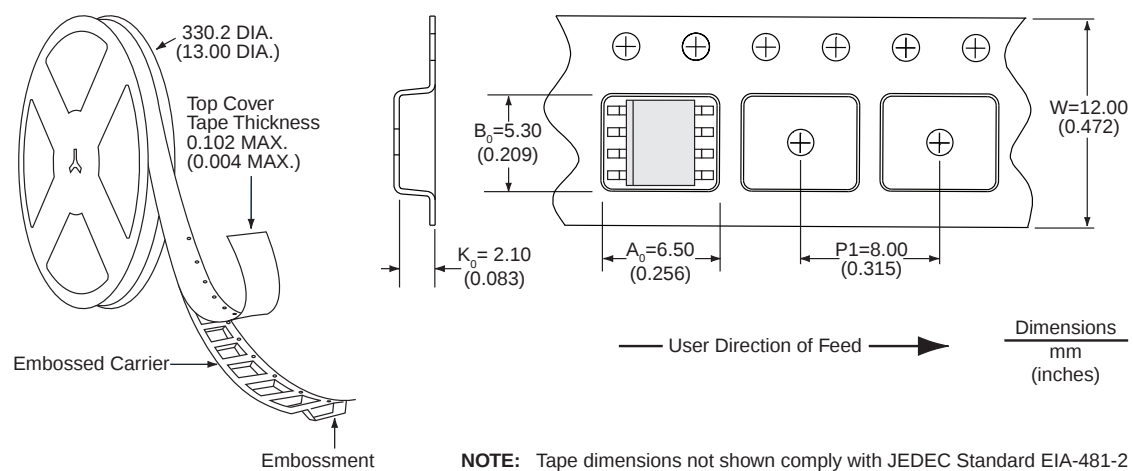


5.5 Mechanical Dimensions

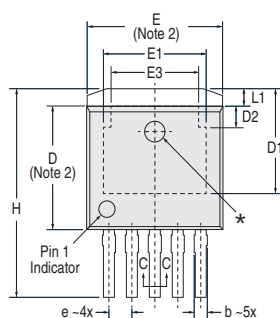
5.5.1 SI (8-Pin Power SOIC with Exposed Metal Back)



5.5.2 SI Package Tape & Reel Information

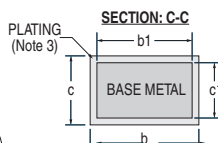
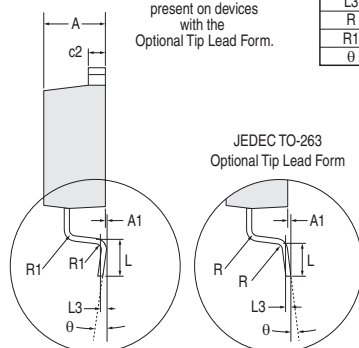
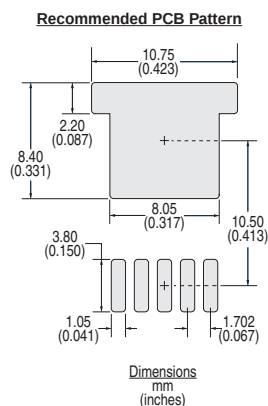


5.5.3 YI (5-Pin TO-263)



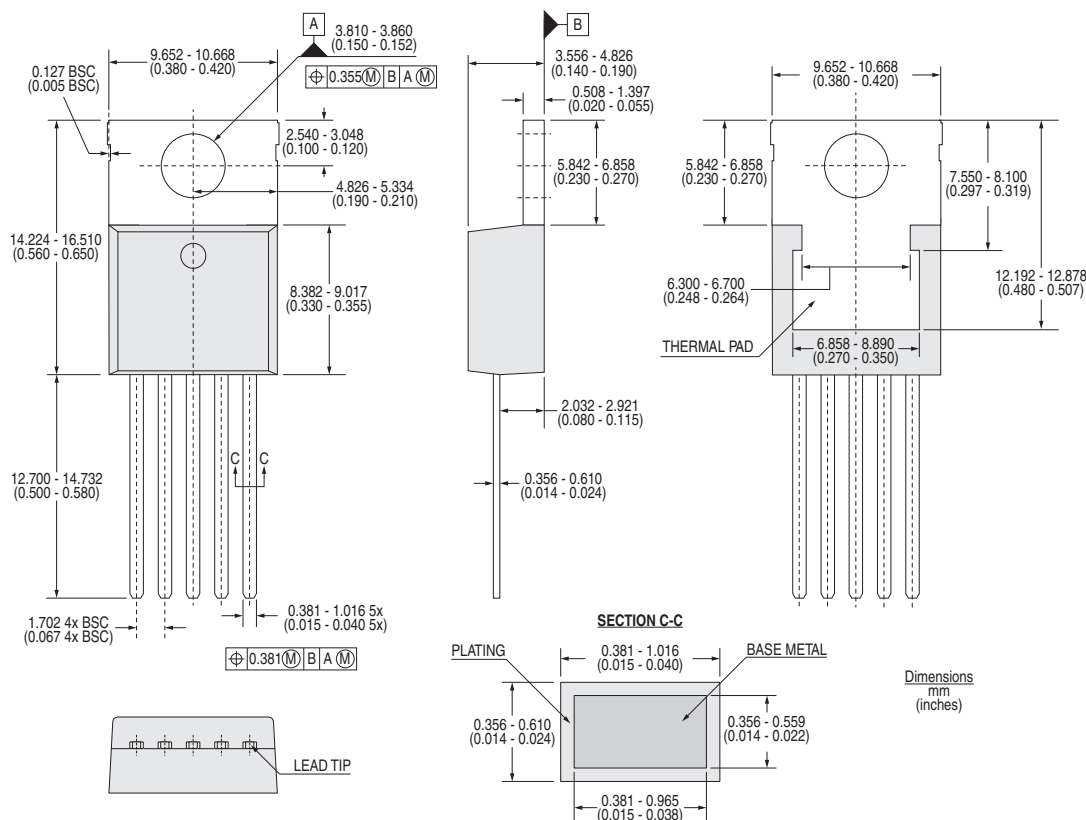
* Circular feature will be present on devices with the Optional Tip Lead Form.

SYMBOL	MM		INCH	
	MIN	MAX	MIN	MAX
A	4.064	4.826	0.160	0.190
A1	0.000	0.254	0.000	0.010
b	0.508	0.991	0.020	0.039
b1	0.508	0.889	0.020	0.035
c	0.381	0.737	0.015	0.029
c1	0.381	0.584	0.015	0.023
c2	1.143	1.651	0.045	0.065
D	8.382	9.652	0.330	0.380
D1	6.858	7.700	0.270	0.303
D2	1.358	1.562	0.053	0.062
E	9.652	10.668	0.380	0.420
E1	6.223	8.000	0.245	0.315
E3	5.092	6.869	0.200	0.270
e	1.702 BSC		0.067 BSC	
H	14.605	15.875	0.575	0.625
L	1.778	2.794	0.070	0.110
L1	1.000	1.676	0.039	0.066
L3	0.254 BSC		0.010 BSC	
R	0.460 TYP		0.018 TYP	
R1	0.506 TYP		0.02 TYP	
A	°	R°	°	R°

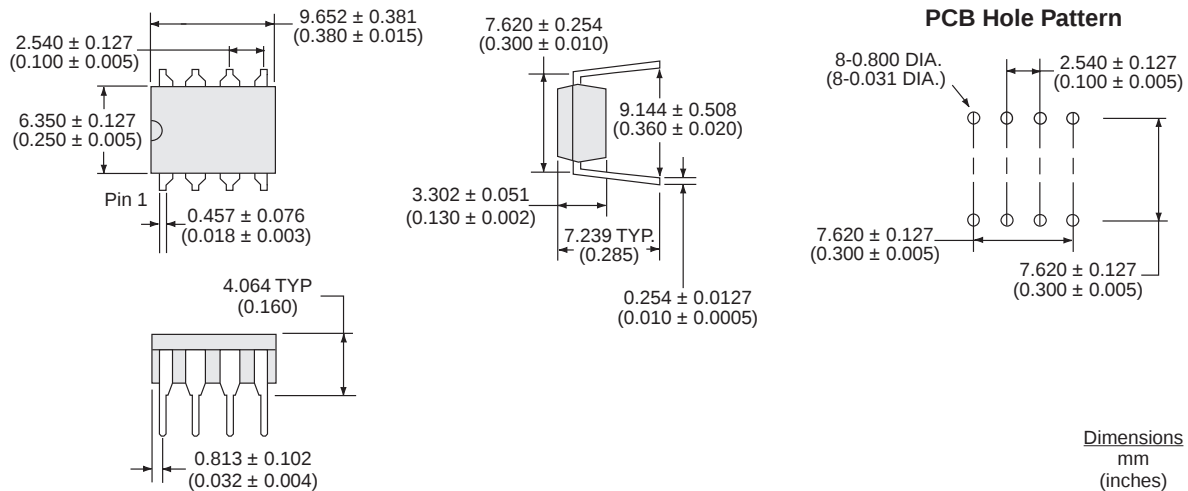


- NOTES:
1. Reference JEDEC TO-263 Type "BA".
 2. Dimension does not include mold flash; mold flash shall not exceed 0.127mm (0.005 inch) per side.
 3. Minimum plating: 1000 microinches.
 4. Controlling dimension: millimeters.

5.5.4 CI (5-Pin TO-220)



5.5.5 PI (8-Pin DIP)



For additional information please visit our website at: www.ixysic.com

IXYS Integrated Circuits Division makes no representations or warranties with respect to the accuracy or completeness of the contents of this publication and reserves the right to make changes to specifications and product descriptions at any time without notice. Neither circuit patent licenses nor indemnity are expressed or implied. Except as set forth in IXYS Integrated Circuits Division's Standard Terms and Conditions of Sale, IXYS Integrated Circuits Division assumes no liability whatsoever, and disclaims any express or implied warranty, relating to its products including, but not limited to, the implied warranty of merchantability, fitness for a particular purpose, or infringement of any intellectual property right.

The products described in this document are not designed, intended, authorized or warranted for use as components in systems intended for surgical implant into the body, or in other applications intended to support or sustain life, or where malfunction of IXYS Integrated Circuits Division's product may result in direct physical harm, injury, or death to a person or severe property or environmental damage. IXYS Integrated Circuits Division reserves the right to discontinue or make changes to its products at any time without notice.

Specification: DS-IXD_614-R08
©Copyright 2017, IXYS Integrated Circuits Division
All rights reserved. Printed in USA.
10/25/2017